

PS9123
HIGH CMR, 15 Mbps TOTEM POLE OUTPUT TYPE, 5-PIN SOP (SO-5) PHOTOCOUPLER

R08DS0030EJ0100 Rev.1.00 Aug 14, 2012

DESCRIPTION

The PS9123 is an optically coupled high-speed, totem pole output isolator containing a GaAlAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

The PS9123 is specified high CMR, high CTR and pulse width distortion with operating temperature.

<R> FEATURES

- High common mode transient immunity (CM_H, CM_L = $\pm 20 \text{ kV/}\mu\text{s}$ TYP.)
- Small package (SO-5)
- Pulse width distortion ($|t_{PHL} t_{PLH}| = 4 \text{ ns TYP.}$)
- High-speed (15 Mbps)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Totem pole output
- Embossed tape product: PS9123-F3 : 2 500 pcs/reel
- Pb-Free product
- · Safety standards
 - UL approved: File No. E72422
 - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
 - DIN EN60747-5-5 (VDE0884-5): 2011-11 approved No. 40008902 (Option)

PIN CONNECTION (Top View) 5 4 3 1. Anode 2. Cathode 3. GND 4. Vo 5. Vcc

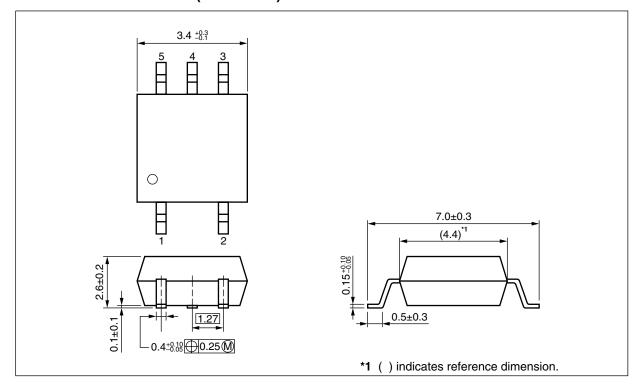
TRUTH TABLE

LED	Output
ON	L
OFF	Н

APPLICATIONS

- PLC
- Inverter
- AC servo

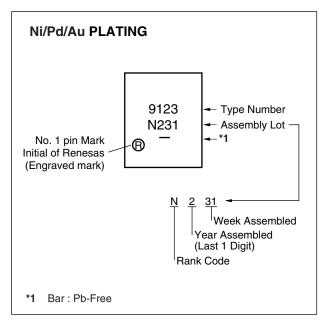
<R> PACKAGE DIMENSIONS (UNIT: mm)



<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	4.2 mm
Outer Creepage Distance	4.2 mm
Isolation Distance	0.2 mm

<R> MARKING EXAMPLE



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*1}
PS9123	PS9123-AX	Pb-Free	20 pcs (Tape 20 pcs cut)	Standard products	PS9123
PS9123-F3	PS9123-F3-AX	(Ni/Pd/Au)	Embossed Tape 2 500 pcs/reel	(UL, CSA approved)	
PS9123-V	PS9123-V-AX		20 pcs (Tape 20 pcs cut)	DIN EN60747-5-5	
PS9123-V-F3	PS9123-V-F3-AX		Embossed Tape 2 500 pcs/reel	(VDE0884-5): 2011-11 Approved (Option)	

Note: *1. For the application of the Safety Standard, following part number should be used.

<R> ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter		Ratings	Unit
Diode	Forward Current *1	I _F	20	mA
	Reverse Voltage	V_R	5	V
Detector	Supply Voltage	V_{CC}	7	V
	Output Voltage	Vo	7	V
High Level Output Current		I _{OH}	-5	mA
Low Level Output Current		I _{OL}	13	mA
Power Dissipation *2		Pc	130	mW
Isolation Voltage *3		BV	3 750	Vr.m.s.
Operating Ambient Temperature		T _A	-40 to +100	°C
Storage T	Storage Temperature		-55 to +125	°C

Notes: *1. Reduced to 0.19 mA/°C at $T_A = 60$ °C or more.

<R> RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
High Level Input Current	I _{FH}	7.5		12.5	mA
Low Level Input Voltage	V_{FL}	0		0.8	٧
Supply Voltage	V _{CC}	4.5	5.0	5.5	٧
TTL (loads)	N			3	

^{*2.} $T_A = -40$ to +100°C, applies to output pin V_O and power supply pin V_{CC} . Reduced to 2.4 mW/°C at $T_A = 70$ °C or more.

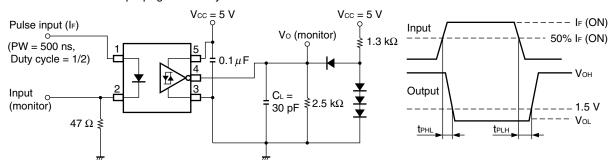
^{*3}. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.

$_{<\text{R>}}$ ELECTRICAL CHARACTERISTICS (T_A = -40 to +100°C, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V_{F}	I _F = 10 mA, T _A = 25°C	1.3	1.55	1.8	V
	Reverse Current	I_R	$V_R = 3 \text{ V}, T_A = 25^{\circ}\text{C}$			10	μΑ
Terminal Capacitance		Ct	$f = 1 \text{ MHz}, V_F = 0 \text{ V}, T_A = 25^{\circ}\text{C}$		30		рF
Detector	High Level Output	I _{OH}	$V_{CC} = V_{O} = 5.5 \text{ V},$		0.05	100	μΑ
	Current		$I_F = 0 \text{ mA}$				
	High Level Output	V_{OH}	$V_{CC} = 4.5 \text{ V}, I_F = 0 \text{ mA},$	2.4	3.0		٧
	Voltage		$I_{OH} = -2 \text{ mA}$				
	Low Level Output	V_{OL}	$V_{CC} = 4.5 \text{ V}, I_F = 7 \text{ mA},$		0.25	0.6	V
	Voltage		$I_{OL} = 8 \text{ mA}$				
	High Level Supply	I_{CCH}	$V_{CC} = 5.5 \text{ V}, I_F = 0 \text{ mA},$		4	7	mA
	Current		V _O = open				
	Low Level Supply	I_{CCL}	$V_{CC} = 5.5 \text{ V}, I_F = 10 \text{ mA},$		6	10	mA
	Current		V _O = open				
	High Level Output Short	I _{OSH}	$V_{CC} = 5.5 \text{ V}, V_O = GND,$		-43		mA
	Circuit Current		$I_F = 0 \text{ mA}, 10 \text{ ms or less}$				
Circuit Current I _F = 8 mA, 10		$V_{CC} = V_{O} = 5.5 \text{ V},$		28		mA	
			$I_F = 8 \text{ mA}$, 10 ms or less			_	_
Coupled	Threshold Input Voltage	I _{FHL}	$V_{CC} = 5 \text{ V}, V_{O} = 0.6 \text{ V}$		2.3	5	mA
	(H → L)	-	V 41.V 511 40 : 000/	4011			
	Isolation Resistance	R _{I-O}	$V_{I-O} = 1 \text{ kV}_{DC}, \text{ RH} = 40 \text{ to } 60\%,$ $T_A = 25^{\circ}\text{C}$	10 ¹¹			Ω
	Isolation Capacitance	$C_{\text{I-O}}$	$V = 0 V, f = 1 MHz, T_A = 25^{\circ}C$		0.6		pF
	Propagation Delay Time $(H \rightarrow L)^{2}$	t _{PHL}	$V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}$	10	28	60	ns
	Propagation Delay Time $(L \rightarrow H)^{2}$	t _{PLH}	$V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}$	10	32	60	ns
	Pulse Width Distortion (PWD)*2	t _{PHL} —t _{PLH}	$V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}$		4	30	ns
	Common Mode	СМн	$V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C},$	15	20		kV/μs
	Transient Immunity at		$I_F = 0 \text{ mA}, V_{O \text{ (MIN.)}} = 2 \text{ V},$,
	High Level Output ^{*3}		$V_{CM} = 1 \text{ kV}$				
	Common Mode	CM_L	$V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C},$	15	20		kV/μs
	Transient Immunity at		$I_F=7.5~mA,~V_{O~(MAX.)}=0.8~V, \label{eq:interpolation}$				
	Low Level Output ^{*3}		$V_{CM} = 1 \text{ kV}$				

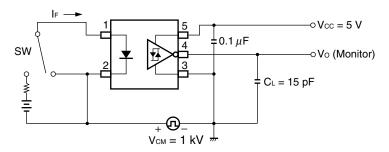
Notes: *1. Typical values at $T_A = 25^{\circ}C$

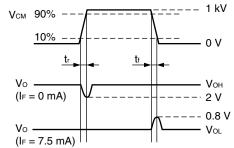
*2. Test circuit for propagation delay time



C∟ includes probe and stray wiring capacitance.

*3. Test circuit for common mode transient immunity

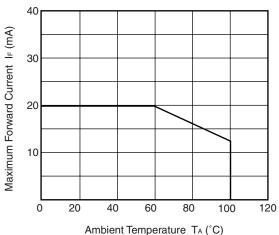




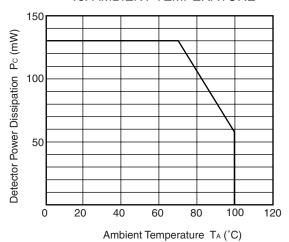
C∟ includes probe and stray wiring capacitance.

<R> TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

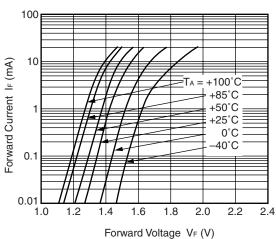




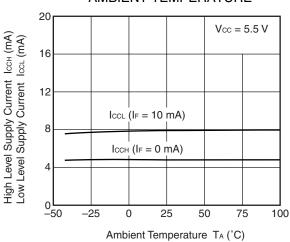
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



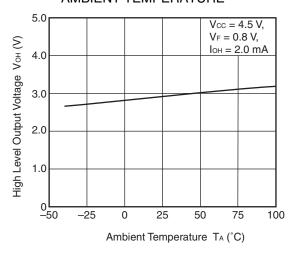
FORWARD CURRENT vs. FORWARD VOLTAGE



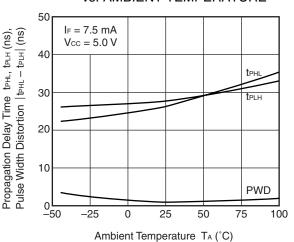
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



HIGH LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE

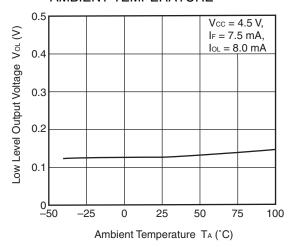


PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE

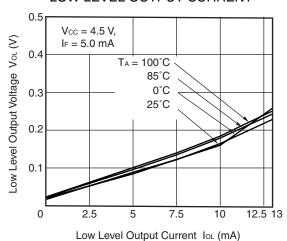


Remark The graphs indicate nominal characteristics.

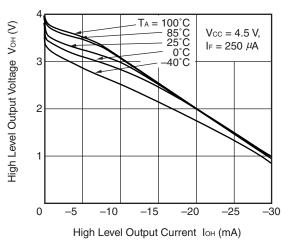
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



LOW LEVEL OUTPUT VOLTAGE vs. LOW LEVEL OUTPUT CURRENT

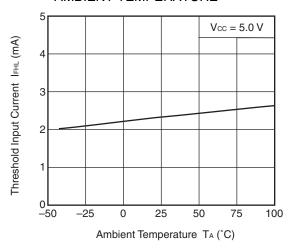


HIGH LEVEL OUTPUT VOLTAGE vs. HIGH LEVEL OUTPUT CURRENT

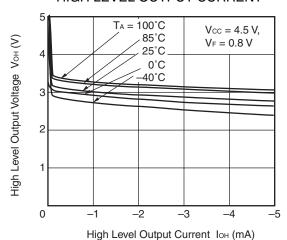


Remark The graphs indicate nominal characteristics.

THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE

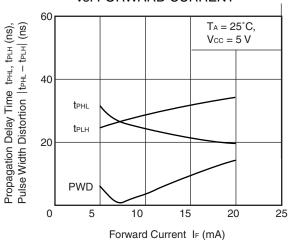


HIGH LEVEL OUTPUT VOLTAGE vs. HIGH LEVEL OUTPUT CURRENT

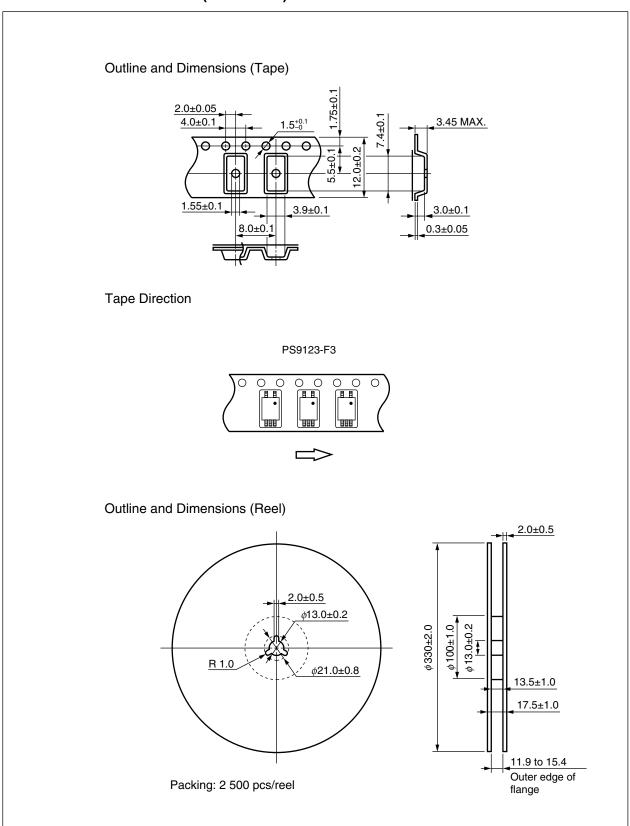


riigii Level Output Current Ton (IIIA)

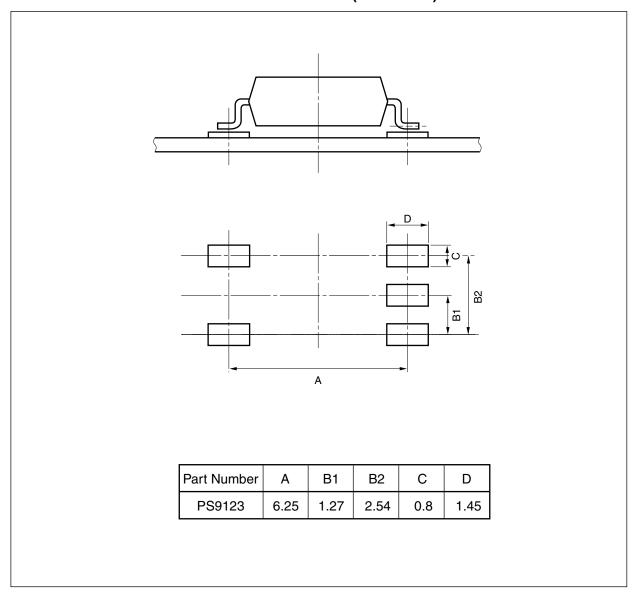
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. FORWARD CURRENT



TAPING SPECIFICATIONS (UNIT: mm)



<R>> RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering

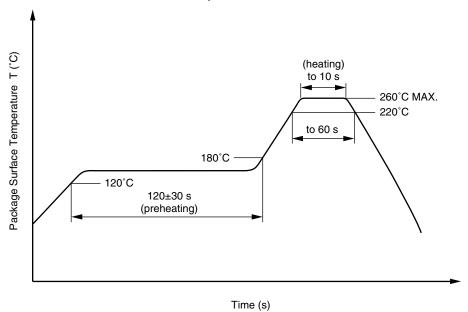
Peak reflow temperature
 260°C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less
 Time of temperature higher than 220°C 60 seconds or less

Time to preheat temperature from 120 to 180°C
 Number of reflows
 Three or less

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% or less is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% or less is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature) 350°C or below

• Time (each pin) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% or less is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions Regarding Noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of 0.1 μ F or more is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is 10 mm or less.
- 3. Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/100/21	
Dielectric strength			
maximum operating isolation voltage	U _{IORM}	707	V_{peak}
Test voltage (partial discharge test, procedure a for type test and	U_pr	1 131	V_{peak}
random test)			
$U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_pr	1 326	V_{peak}
$U_{pr} = 1.875 \times U_{IORM}, P_d < 5 pC$			
Highest permissible overvoltage	U _{TR}	6 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303	CTI	175	
Part 11))			
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T _{stg}	-55 to +125	°C
Operating temperature range	T _A	-40 to +100	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see			
thermal derating curve)			
Package temperature	Tsi	150	°C
Current (input current I _F , P _{si} = 0)	Isi	200	mA
Power (output or total power dissipation)	Psi	300	mW
Isolation resistance			
$V_{IO} = 500 \text{ V dc at } T_A = Tsi$	Ris MIN.	10 ⁹	Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

Revision History

PS9123 Data Sheet

		Description		
Rev.	Date	Page	Summary	
0.01	Jan 29, 2011	_	First edition issued	
1.00	Aug 14, 2012	Throughout	"Preliminary Data Sheet" is changed to "Data Sheet."	
		p.1	Modification of FEATURES	
		p.2	Modification of PACKAGE DIMENSIONS	
			Modification of PHOTOCOUPLER CONSTRUCTION	
			Modification of MARKING EXAMPLE	
		p.3	Addition of ORDERING INFORMATION	
			Modification of ABSOLUTE MAXIMUM RATINGS	
			Modification of RECOMMENDED OPERATING CONDITIONS	
		pp.4, 5	Modification of ELECTRICAL CHARACTERISTICS	
		pp.6, 7	Addition of TYPICAL CHARACTERISTICS	
		p.8	Addition of TAPING SPECIFICATIONS	
		p.9	Addition of RECOMMENDED MOUNT PAD DIMENSIONS	
		pp.10, 11	Addition of NOTES ON HANDLING	
		p.12	Addition of SPECIFICATION OF VDE MARKS LICENSE DOCUMENT	

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